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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

P

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10020460	12/18/2001	257	012	2811	Rane

**APPLICANTS: Ito Jun; Chiyo Toshiaki; Shibata Naoki; Watanabe Hiroshi; Asami Shizuyo; Asami Shinya;

**CONTINUING DATA VERIFIED:

THIS APPLICATION IS A DIV OF 09/518,724 03/03/2000 U.S. Patent No. 6,426,512

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** FOREIGN APPLICATIONS VERIFIED:

JAPAN HEI. 11-058128 03/05/1999

JAPAN HEI. 11-060206 03/08/1999

JAPAN HEI. 11-061155 03/09/1999

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO
Foreign priority claimed 35 USC 119 conditions met Verified and Acknowledged Examiners's initials		<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input type="checkbox"/> no	P 282612 T36-141808M/KOH
TITLE : Group III nitride compound semiconductor device			

U.S.DEP.T. OF COMM./PAT.& TM-PTO-436L(Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Fig.s Drwg.
TERMINAL DISCLAIMER		Application Examiner	
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